



30C02CH

Bipolar Transistor 30V, 0.7A, Low $V_{CE(sat)}$ NPN Single CPH3

ON Semiconductor®

<http://onsemi.com>

Applications

- Low-frequency Amplifier, high-speed switching, small motor drive

Features

- Large current capacity
- Low collector-to-emitter saturation voltage (resistance) $R_{CE(sat)}$ typ.=330m Ω [$I_C=0.7A$, $I_B=35mA$]
- Ultrasmall package facilitates miniaturization in end products
- Small ON-resistance (R_{on})

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

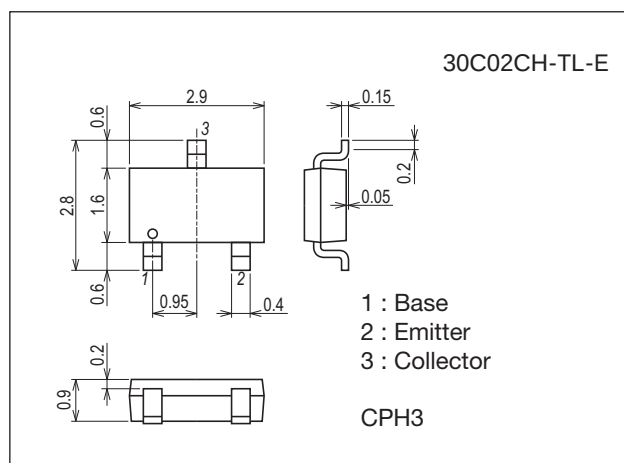
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		40	V
Collector-to-Emitter Voltage	V_{CEO}		30	V
Emitter-to-Base Voltage	V_{EBO}		5	V
Collector Current	I_C		700	mA
Collector Current (Pulse)	I_{CP}		1.4	A
Collector Dissipation	P_C	Mounted on a ceramic board (600mm ² ×0.8mm)	700	mW
Junction Temperature	T_j		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

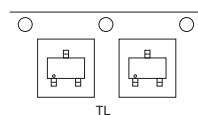
7015A-003



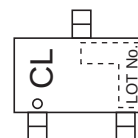
Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

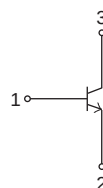
Packing Type: TL



Marking



Electrical Connection

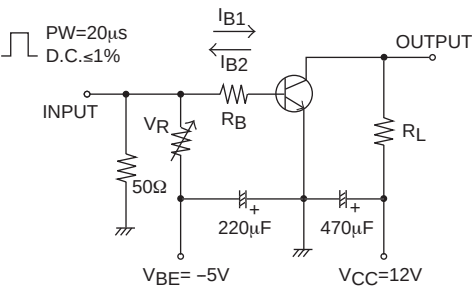


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Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V _{CB} =30V, I _E =0A			100	nA
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			100	nA
DC Current Gain	h _{FE}	V _{CE} =2V, I _C =50mA	300		800	
Gain-Bandwidth Product	f _T	V _{CE} =10V, I _C =50mA		540		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		3.3		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =200mA, I _B =10mA		85	190	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =200mA, I _B =10mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C =10μA, I _E =0A	40			V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =1mA, R _{BE} =∞	30			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =10μA, I _C =0A	5			V
Turn-On Time	t _{on}	See specified Test Circuit.		35		ns
Storage Time	t _{stg}			255		ns
Fall Time	t _f			40		ns

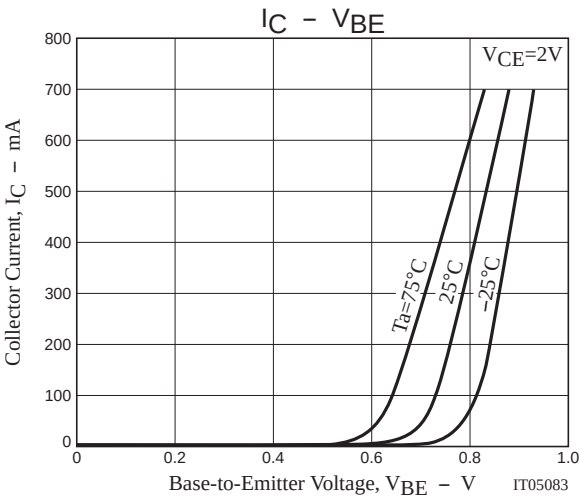
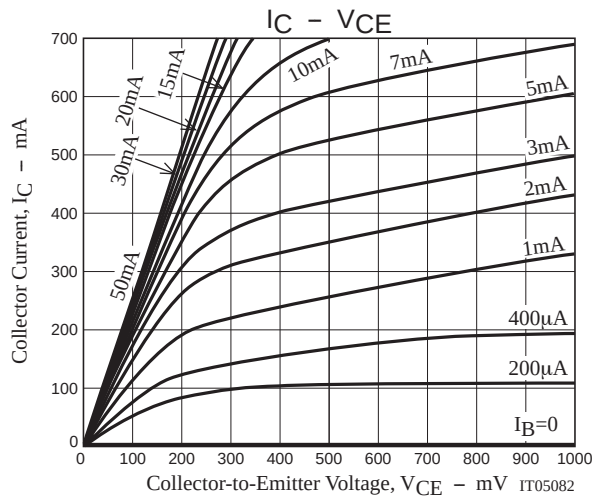
Switching Time Test Circuit

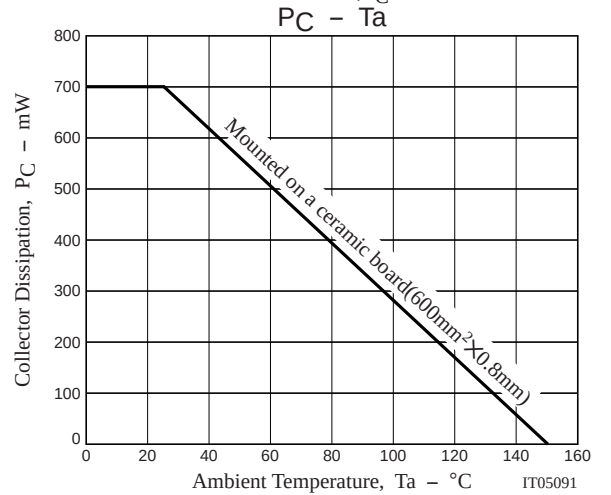
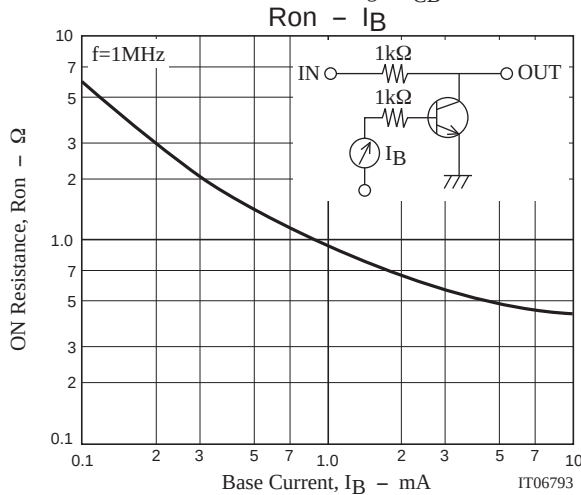
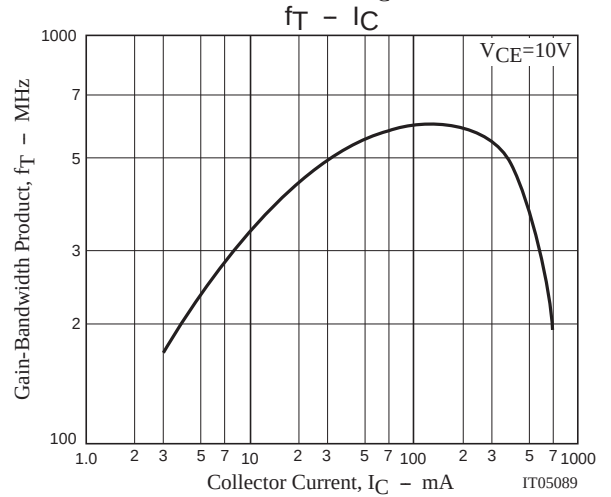
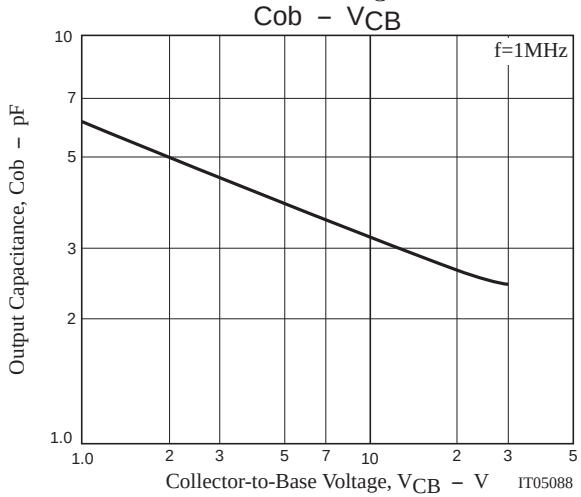
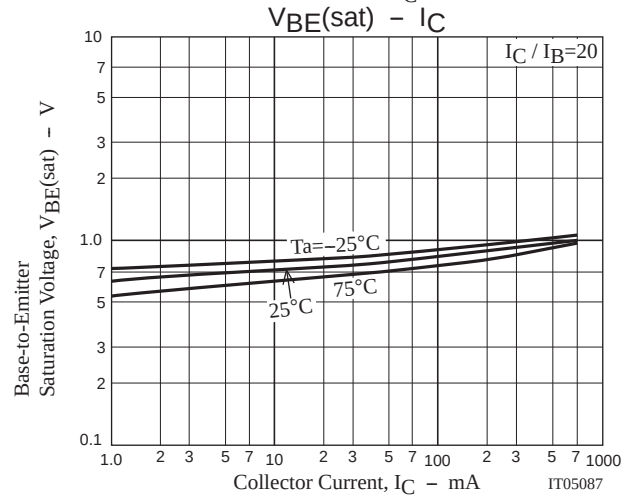
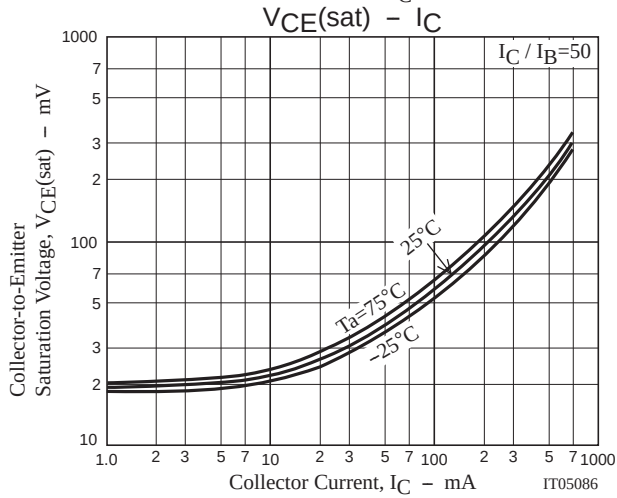
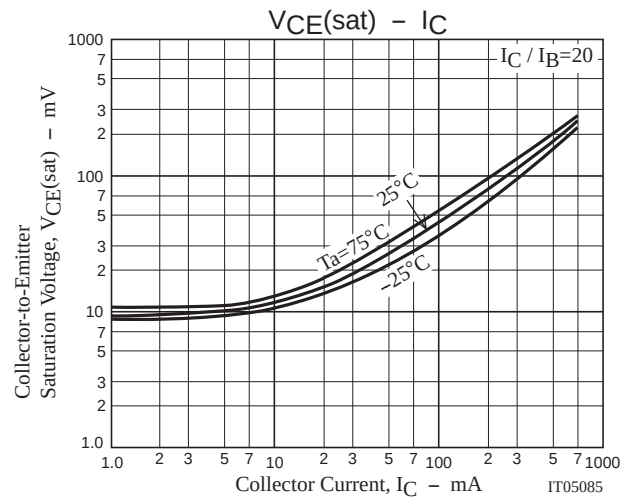
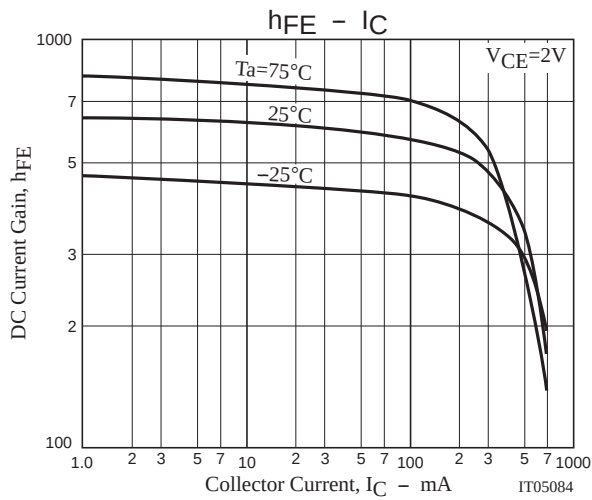


$I_C = 20I_{B1} = -20I_{B2} = 300\text{mA}$

Ordering Information

Device	Package	Shipping	memo
30C02CH-TL-E	CPH3	3,000pcs./reel	Pb Free





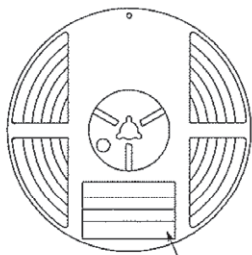
Embossed Taping Specification

30C02CH-TL-E

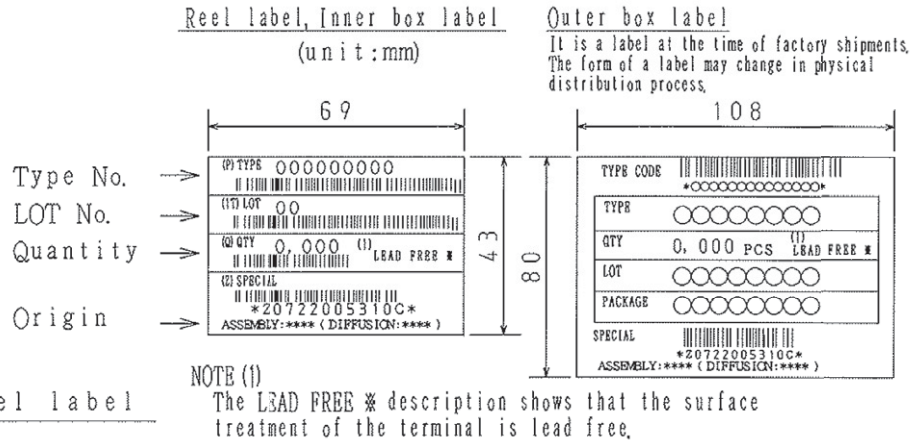
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH3	CPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



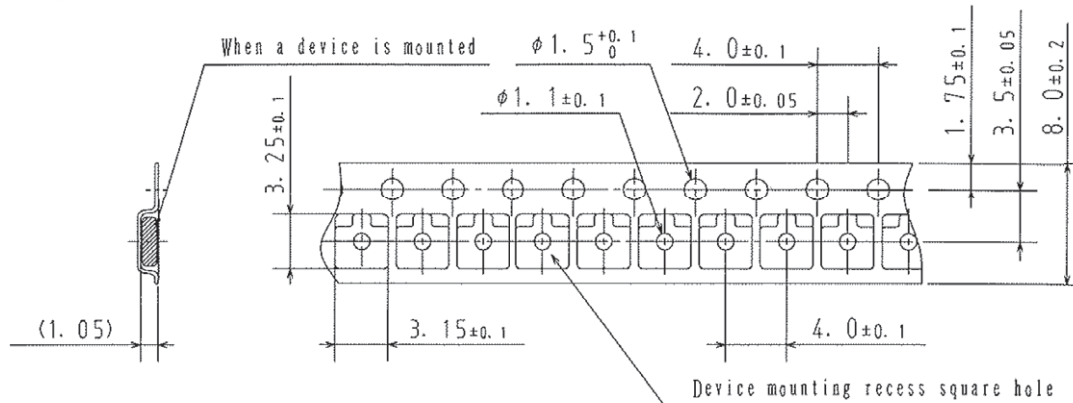
Reel label



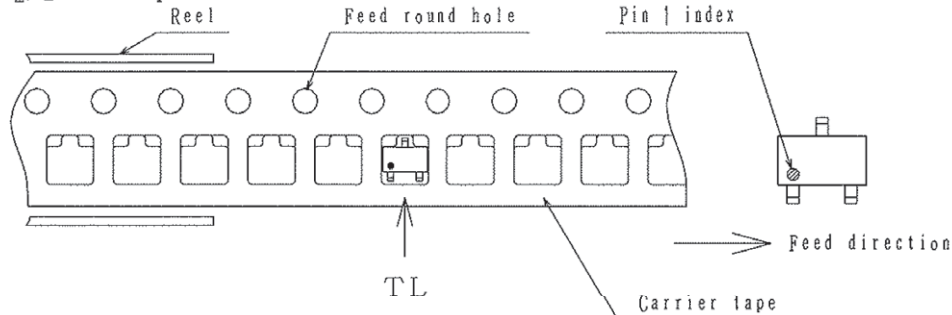
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)

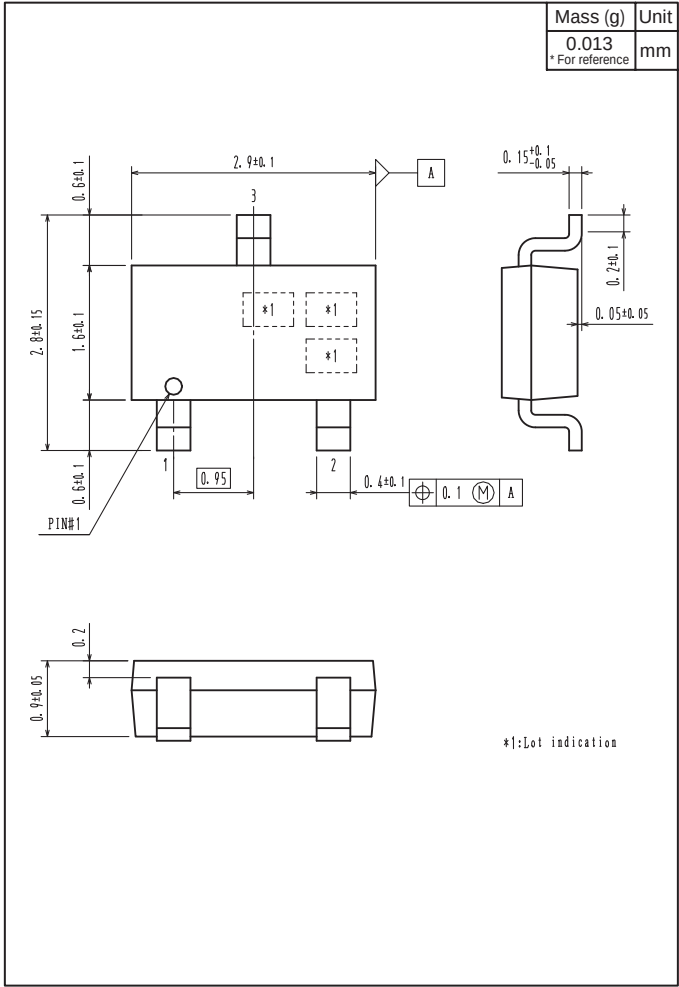


2-2. Device placement direction

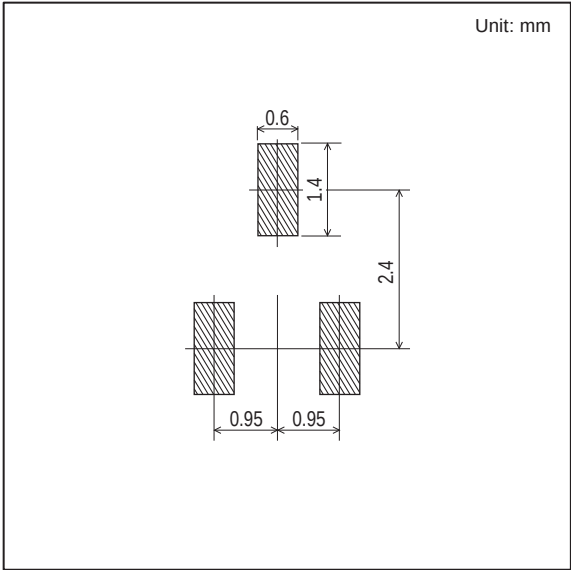


Those with one electrode terminal on the feed hole side.....TL

Outline Drawing
30C02CH-TL-E



Land Pattern Example



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